# NSN 5961-01-443-3324

Transistor - Page 1 of 1



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## Inclosure Material:

Metal

**Overall Length:** 

1.573 inches

## **Overall Height:**

0.360 inches

## **Overall Width:**

1.050 inches

## Mounting Facility Quantity:

2

#### Internal Configuration:

Field effect

#### Electrode Internally-electrically Connected To Case:

Drain

#### **Mounting Method:**

#### Unthreaded hole

Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

200.0 drain to gate voltage and 200.0 drain to source voltage and 10.0 gate to source voltage

#### **Current Rating Per Characteristic:**

20.00 amperes off-state current, peak

#### **Power Rating Per Characteristic:**

75.0 watts total power dissipation

### Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

#### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

### Terminal Type And Quantity:

2 pin and 1 case

#### **Specification Data:**

81349-mil-s-19500/566 government specification

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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